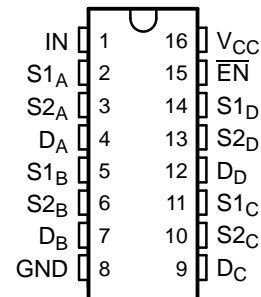


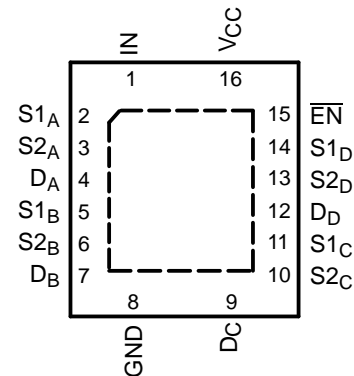
## FEATURES

- Low Differential Gain and Phase ( $D_G = 0.82\%$ ,  $D_P = 0.1$  Degree Typ)
- Wide Bandwidth (BW = 300 MHz Min)
- Low Crosstalk ( $X_{TALK} = -80$  dB Typ)
- Low Power Consumption ( $I_{CC} = 10$   $\mu$ A Max)
- Bidirectional Data Flow With Near-Zero Propagation Delay
- Low ON-State Resistance ( $r_{on} = 3$   $\Omega$  Typ)
- Rail-to-Rail Switching on Data I/O Ports (0 to  $V_{CC}$ )
- $V_{CC}$  Operating Range From 3 V to 3.6 V
- $I_{off}$  Supports Partial-Power-Down Mode Operation
- Data and Control Inputs Provide Undershoot Clamp Diode
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
  - 2000-V Human-Body Model (A114-B, Class II)
  - 1000-V Charged-Device Model (C101)
- Suitable for Both RGB and Composite-Video Switching

**D, DBQ, DGV, OR PW PACKAGE  
(TOP VIEW)**



**RGY PACKAGE  
(TOP VIEW)**



## DESCRIPTION/ORDERING INFORMATION

The TS3V330 video switch is a 4-bit 1-of-2 multiplexer/demultiplexer, with a single switch-enable ( $\overline{EN}$ ) input. When  $\overline{EN}$  is low, the switch is enabled and the D port is connected to the S port. When  $\overline{EN}$  is high, the switch is disabled and the high-impedance state exists between the D and S ports. The select (IN) input controls the data path of the multiplexer/demultiplexer.

Low differential gain and phase make this switch ideal for composite and RGB video applications. This device has wide bandwidth and low crosstalk, making it suitable for high-frequency applications as well.

## ORDERING INFORMATION

$T_A$	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	QFN – RGY	Tape and reel	TS3V330RGYR	TF330
	SOIC – D	Tube	TS3V330D	TS3V330
		Tape and reel	TS3V330DR	
	SSOP (QSOP) – DBQ	Tape and reel	TS3V330DBQR	TF330
	TSSOP – PW	Tube	TS3V330PW	TF330
		Tape and reel	TS3V330PWR	
	TVSOP – DGV	Tape and reel	TS3V330DGV	TF330

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

# TS3V330

## QUAD SPDT WIDE-BANDWIDTH VIDEO SWITCH WITH LOW ON-STATE RESISTANCE

SCDS162C–MAY 2004–REVISED JULY 2005

### DESCRIPTION/ORDERING INFORMATION

This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  feature ensures that damaging current will not backflow through the device when it is powered down. This switch maintains isolation during power off.

To ensure the high-impedance state during power up or power down,  $\overline{EN}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

**FUNCTION TABLE**

INPUTS		INPUT/OUTPUT D	FUNCTION
$\overline{EN}$	IN		
L	L	S1	D port = S1 port
L	H	S2	D port = S2 port
H	X	Z	Disconnect

**PIN DESCRIPTION**

NAME	DESCRIPTION
S1, S2	Analog video I/Os
D	Analog video I/Os
IN	Select input
$\overline{EN}$	Switch-enable input

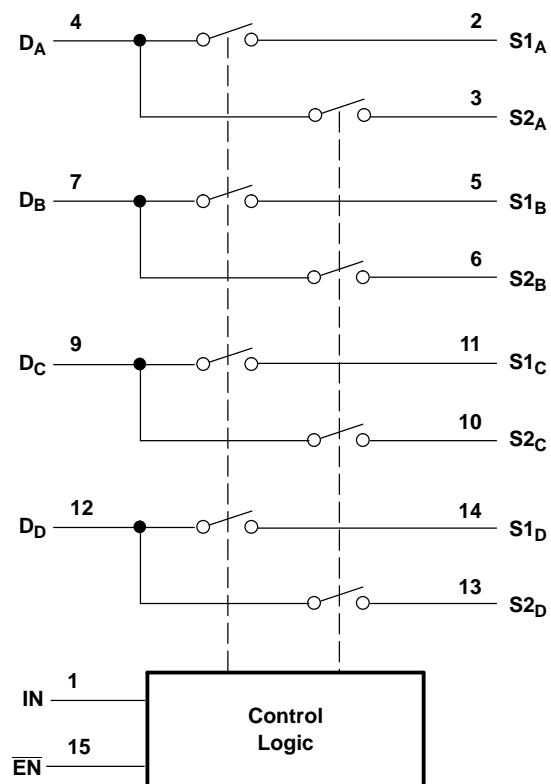
**PARAMETER DEFINITIONS**

PARAMETER	DESCRIPTION
$R_{on}$	Resistance between the D and S ports, with the switch in the ON state
$I_{OZ}$	Output leakage current measured at the D and S ports, with the switch in the OFF state
$I_{OS}$	Short-circuit current measured at the I/O pins
$V_{IN}$	Voltage at IN
$V_{EN}$	Voltage at $\overline{EN}$
$C_{IN}$	Capacitance at the control ( $\overline{EN}$ , IN) inputs
$C_{OFF}$	Capacitance at the analog I/O port when the switch is OFF
$C_{ON}$	Capacitance at the analog I/O port when the switch is ON
$V_{IH}$	Minimum input voltage for logic high for the control ( $\overline{EN}$ , IN) inputs
$V_{IL}$	Minimum input voltage for logic low for the control ( $\overline{EN}$ , IN) inputs
$V_H$	Hysteresis voltage at the control ( $\overline{EN}$ , IN) inputs
$V_{IK}$	I/O and control ( $\overline{EN}$ , IN) inputs diode clamp voltage
$V_I$	Voltage applied to the D or S pins when D or S is the switch input
$V_O$	Voltage applied to the D or S pins when D or S is the switch output
$I_{IH}$	Input high leakage current of the control ( $\overline{EN}$ , IN) inputs
$I_{IL}$	Input low leakage current of the control ( $\overline{EN}$ , IN) inputs
$I_I$	Current into the D or S pins when D or S is the switch input
$I_O$	Current into the D or S pins when D or S is the switch output
$I_{off}$	Output leakage current measured at the D or S ports, with $V_{CC} = 0$
$t_{ON}$	Propagation delay measured between 50% of the digital input to 90% of the analog output when switch is turned ON
$t_{OFF}$	Propagation delay measured between 50% of the digital input to 90% of the analog output when switch is turned OFF
BW	Frequency response of the switch in the ON state measured at –3 dB
$X_{TALK}$	Unwanted signal coupled from channel to channel. Measured in –dB. $X_{TALK} = 20 \log V_O/V_I$ . This is a nonadjacent crosstalk.
$O_{IRR}$	Off isolation is the resistance (measured in –dB) between the input and output with the switch OFF.
$D_G$	Magnitude variation between analog input and output pins when the switch is ON and the dc offset of composite-video signal varies at the analog input pin. In the NTSC standard, the frequency of the video signal is 3.58 MHz, and dc offset is from 0 to 0.714 V.
$D_P$	Phase variation between analog input and output pins when the switch is ON and the dc offset of composite-video signal varies at the analog input pin. In the NTSC standard, the frequency of the video signal is 3.58 MHz, and dc offset is from 0 to 0.714 V.
$I_{CC}$	Static power-supply current
$I_{CCD}$	Variation of $I_{CC}$ for a change in frequency in the control ( $\overline{EN}$ , IN) inputs
$\Delta I_{CC}$	This is the increase in supply current for each control input that is at the specified voltage level, rather than $V_{CC}$ or GND.

**TS3V330**  
**QUAD SPDT WIDE-BANDWIDTH VIDEO SWITCH**  
**WITH LOW ON-STATE RESISTANCE**

SCDS162C–MAY 2004–REVISED JULY 2005

**FUNCTIONAL DIAGRAM (POSITIVE LOGIC)**



## Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
$V_{CC}$	Supply voltage range	–0.5	4.6	V
$V_{IN}$	Control input voltage range <sup>(2) (3)</sup>	–0.5	4.6	V
$V_{I/O}$	Switch I/O voltage range <sup>(2) (3) (4)</sup>	–0.5	4.6	V
$I_{IK}$	Control input clamp current		–50	mA
$I_{I/O}$	I/O port clamp current		–50	mA
$I_{I/O}$	ON-state switch current <sup>(5)</sup>		±128	mA
	Continuous current through $V_{CC}$ or GND		±100	mA
$\theta_{JA}$	Package thermal impedance	D package <sup>(6)</sup>	73	C/W
		DBQ package <sup>(6)</sup>	90	
		DGV package	120	
		PW package <sup>(6)</sup>	108	
		RGY package <sup>(7)</sup>	39	
$T_{stg}$	Storage temperature range	–65	150	C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltages are with respect to ground, unless otherwise specified.
- (3) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (4)  $V_I$  and  $V_O$  are used to denote specific conditions for  $V_{I/O}$ .
- (5)  $I_I$  and  $I_O$  are used to denote specific conditions for  $I_{I/O}$ .
- (6) The package thermal impedance is calculated in accordance with JESD 51-7.
- (7) The package thermal impedance is calculated in accordance with JESD 51-5.

## Recommended Operating Conditions<sup>(1)</sup>

		MIN	MAX	UNIT
$V_{CC}$	Supply voltage	3	3.6	V
$V_{IH}$	High-level control input voltage (EN, IN)	2	$V_{CC}$	V
$V_{IL}$	Low-level control input voltage (EN, IN)	0	0.8	V
$V_{ANALOG}$	Analog I/O voltage	0	$V_{CC}$	V
$T_A$	Operating free-air temperature	–40	85	°C

- (1) All unused control inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

# TS3V330

## QUAD SPDT WIDE-BANDWIDTH VIDEO SWITCH WITH LOW ON-STATE RESISTANCE

SCDS162C–MAY 2004–REVISED JULY 2005

### Electrical Characteristics

over recommended operating free-air temperature range,  $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$  (unless otherwise noted)

PARAMETER		TEST CONDITIONS <sup>(1)</sup>		MIN	TYP <sup>(2)</sup>	MAX	UNIT
$V_{IK}$	$\overline{EN}$ , IN	$V_{CC} = 3 \text{ V}$ ,	$I_{IN} = -18 \text{ mA}$			-1.8	V
$V_{hys}$	$\overline{EN}$ , IN				150		mV
$I_{IH}$	$\overline{EN}$ , IN	$V_{CC} = 3.6 \text{ V}$ ,	$V_{IN}$ and $V_{EN} = V_{CC}$			$\pm 1$	$\mu\text{A}$
$I_{IL}$	$\overline{EN}$ , IN	$V_{CC} = 3.6 \text{ V}$ ,	$V_{IN}$ and $V_{EN} = \text{GND}$			$\pm 1$	$\mu\text{A}$
$I_{OZ}$ <sup>(3)</sup>		$V_{CC} = 3.6 \text{ V}$ ,	$V_O = 0$ to $3.6 \text{ V}$ , $V_I = 0$ , Switch OFF			$\pm 1$	$\mu\text{A}$
$I_{OS}$ <sup>(4)</sup>		$V_{CC} = 3.6 \text{ V}$ ,	$V_O = 0.5 V_{CC}$ , $V_I = 0$ , Switch ON	50			mA
$I_{off}$		$V_{CC} = 0 \text{ V}$ ,	$V_O = 0$ to $3.6 \text{ V}$ , $V_I = 0$			15	$\mu\text{A}$
$I_{CC}$		$V_{CC} = 3.6 \text{ V}$ ,	$I_{I/O} = 0$ , Switch ON or OFF			10	$\mu\text{A}$
$\Delta I_{CC}$	$\overline{EN}$ , IN	$V_{CC} = 3.6 \text{ V}$ ,	One input at $3.4 \text{ V}$ , Other inputs at $V_{CC}$ or GND			750	$\mu\text{A}$
$I_{CCD}$		$V_{CC} = 3.6 \text{ V}$ , $V_{EN} = \text{GND}$ $V_{IN}$ input switching 50% duty cycle	D and S ports open,			0.45	mA/ MHz
$C_{IN}$	$\overline{EN}$ , IN	$V_{IN}$ of $V_{EN} = 0$ ,	$f = 1 \text{ MHz}$		3.5		pF
$C_{OFF}$	D port	$V_I = 0$ ,	$f = 1 \text{ MHz}$ , Outputs open, Switch OFF		10		pF
	S port				5		
$C_{ON}$		$V_I = 0$ ,	$f = 1 \text{ MHz}$ , Outputs open, Switch ON		17		pF
$r_{on}$ <sup>(5)</sup>		$V_{CC} = 3 \text{ V}$	$V_I = 1 \text{ V}$ , $I_O = 13 \text{ mA}$ , $R_L = 75 \Omega$		5	7	$\Omega$
			$V_I = 2 \text{ V}$ , $I_O = 26 \text{ mA}$ , $R_L = 75 \Omega$		7	10	

(1)  $V_I$ ,  $V_O$ ,  $I_I$ , and  $I_O$  refer to I/O pins.

(2) All typical values are at  $V_{CC} = 5 \text{ V}$  (unless otherwise noted),  $T_A = 25^\circ\text{C}$ .

(3) For I/O ports,  $I_{OZ}$  includes the input leakage current.

(4) The  $I_{OS}$  test is applicable to only one ON channel at a time. The duration of this test is less than one second.

(5) Measured by the voltage drop between the D and S terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (D or S) terminals.

### Switching Characteristics

over recommended operating free-air temperature range,  $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ ,  $R_L = 75 \Omega$ ,  $C_L = 20 \text{ pF}$  (unless otherwise noted) (see [Figure 5](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN	TYP	MAX	UNIT
$t_{ON}$	S	D		2.5	6.5	ns
$t_{OFF}$	S	D		1.1	3.5	ns

### Dynamic Characteristics

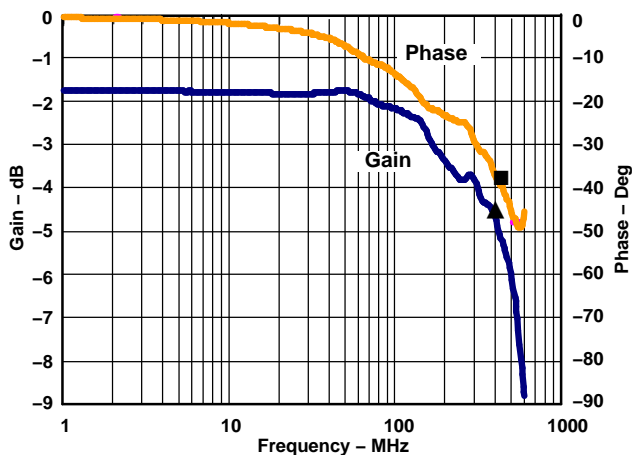
over recommended operating free-air temperature range,  $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS		TYP <sup>(1)</sup>	UNIT
$D_G$ <sup>(2)</sup>	$R_L = 150 \Omega$ ,	$f = 3.58 \text{ MHz}$ , See <a href="#">Figure 6</a>	0.82	%
$D_P$ <sup>(2)</sup>	$R_L = 150 \Omega$ ,	$f = 3.58 \text{ MHz}$ , See <a href="#">Figure 6</a>	0.1	Deg
BW	$R_L = 150 \Omega$ ,	See <a href="#">Figure 7</a>	300	MHz
$X_{TALK}$	$R_L = 150 \Omega$ ,	$f = 10 \text{ MHz}$ , $R_{IN} = 10 \Omega$ , See <a href="#">Figure 8</a>	-80	dB
$O_{IRR}$	$R_L = 150 \Omega$ ,	$f = 10 \text{ MHz}$ , See <a href="#">Figure 9</a>	-50	dB

(1) All typical values are at  $V_{CC} = 5 \text{ V}$  (unless otherwise noted),  $T_A = 25^\circ\text{C}$ .

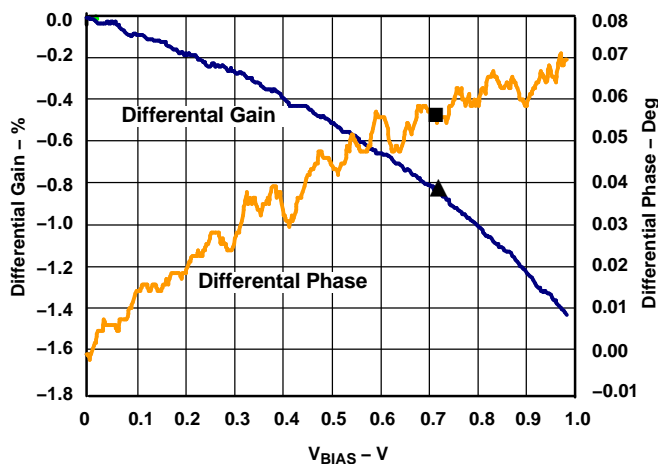
(2)  $D_G$  and  $D_P$  are expressed in absolute magnitude.

## TYPICAL CHARACTERISTICS



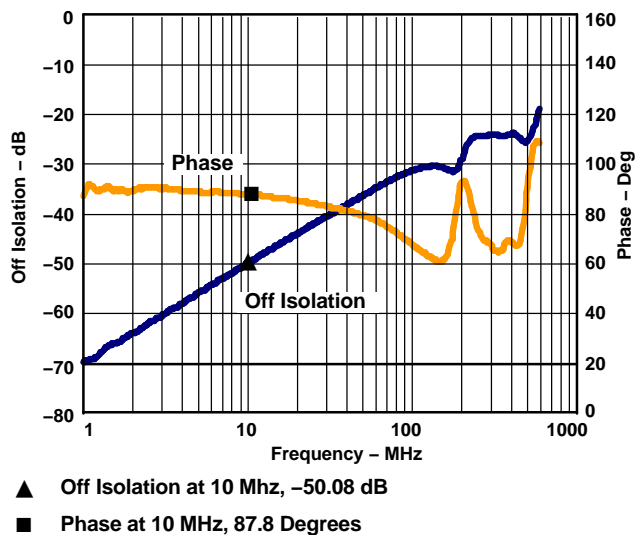
- ▲ Gain 3 dB at 400 MHz
- Phase at 3-dB Frequency, -38.28 Degrees

Figure 1. Gain/Phase vs Frequency

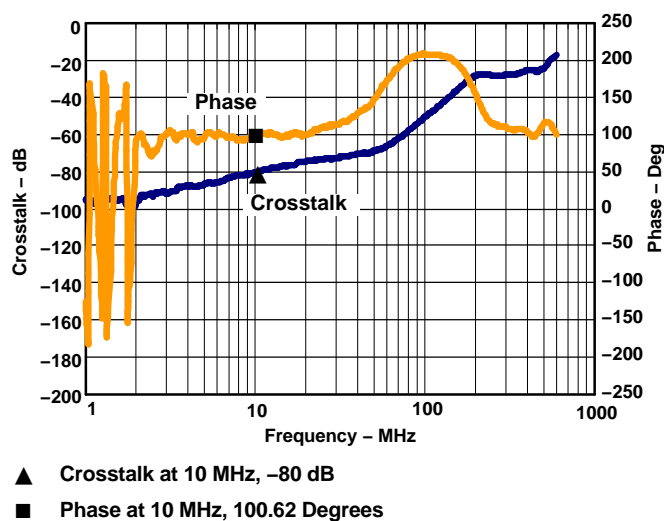


- ▲ Differential Gain at 0.714 V, -0.81%
- Differential Phase at 0.714 V, 0.06 Degree

Figure 2. Differential Gain/Phase vs  $V_{BIAS}$



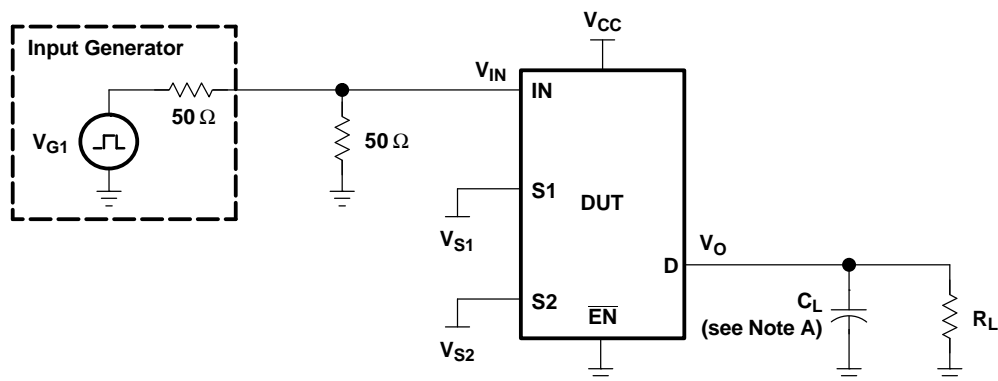
**Figure 3. Off Isolation vs Frequency**



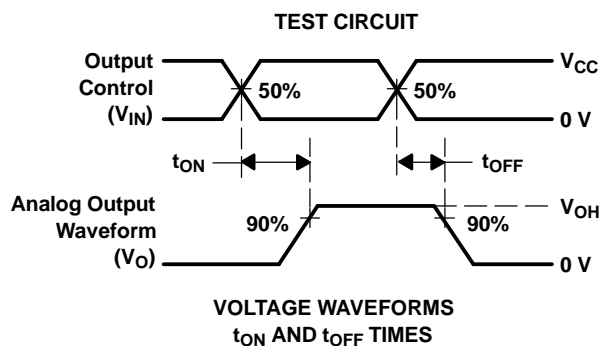
**Figure 4. Crosstalk vs Frequency**



## PARAMETER MEASUREMENT INFORMATION



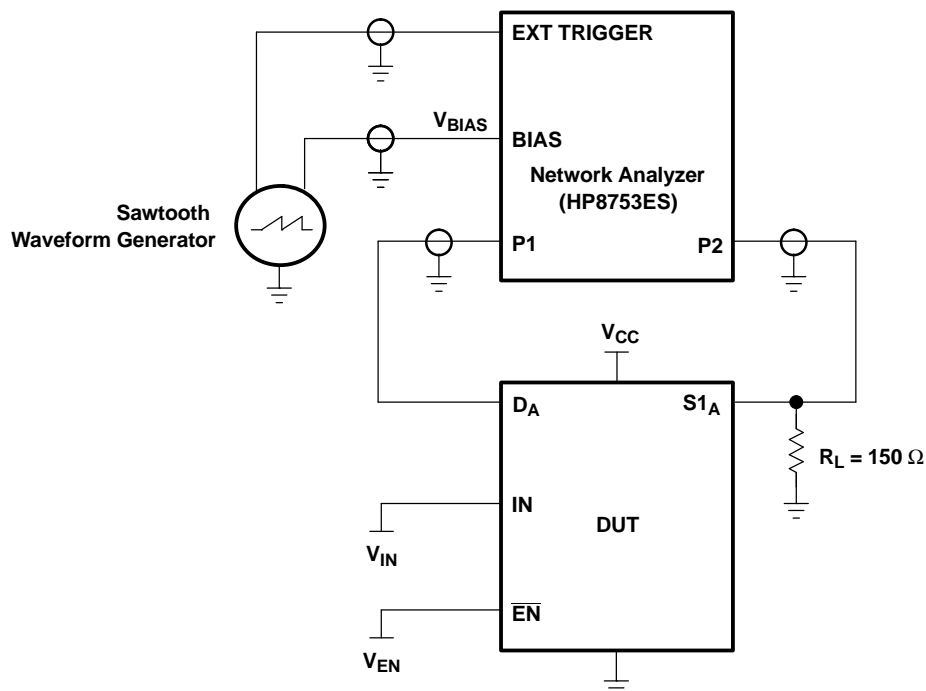
TEST	V <sub>CC</sub>	R <sub>L</sub>	C <sub>L</sub>	V <sub>S1</sub>	V <sub>S2</sub>
t <sub>ON</sub>	3.3 V ± 0.3 V	75	20	GND	V <sub>CC</sub>
	3.3 V ± 0.3 V	75	20	V <sub>CC</sub>	GND
t <sub>OFF</sub>	3.3 V ± 0.3 V	75	20	GND	V <sub>CC</sub>
	3.3 V ± 0.3 V	75	20	V <sub>CC</sub>	GND



- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.  
B. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z<sub>O</sub> = 50 Ω, t<sub>r</sub> ≤ 2.5 ns, t<sub>f</sub> ≤ 2.5 ns.  
C. The outputs are measured one at a time, with one transition per measurement.

**Figure 5. Test Circuit and Voltage Waveforms**

## PARAMETER MEASUREMENT INFORMATION



NOTE: For additional information on measurement method, refer to the TI application report, *Measuring Differential Gain and Phase*, literature number SLOA040.

**Figure 6. Test Circuit for Differential Gain/Phase Measurement**

Differential gain and phase are measured at the output of the ON channel. For example, when  $V_{IN} = 0$ ,  $V_{EN} = 0$ , and  $D_A$  is the input, the output is measured at  $S1_A$ .

### HP8753ES Setup

Average = 20  
RBW = 300 Hz  
ST = 1.381 s  
P1 = -7 dBm  
CW frequency = 3.58 MHz

### Sawtooth Waveform Generator Setup

$V_{BIAS} = 0$  to 1 V  
Frequency = 0.905 Hz

## PARAMETER MEASUREMENT INFORMATION

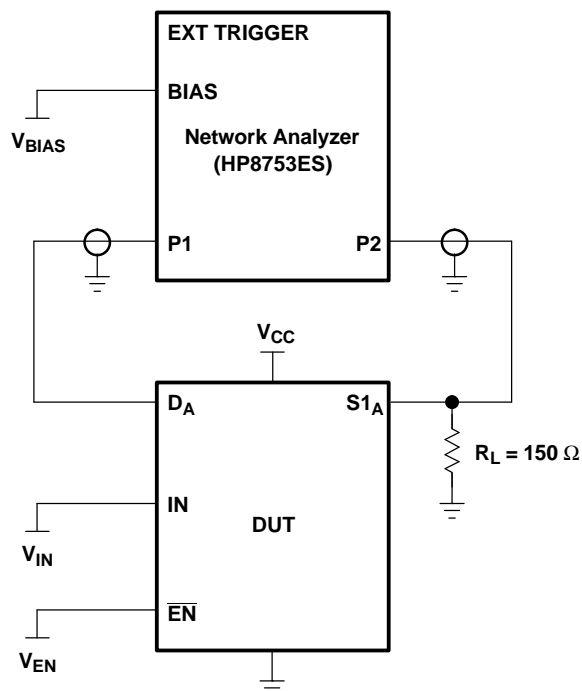


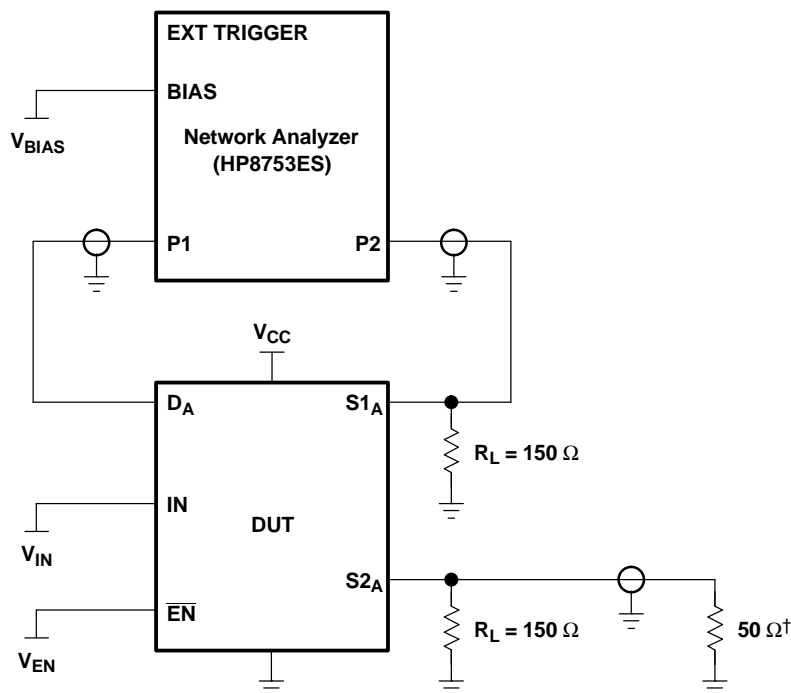
Figure 7. Test Circuit for Frequency Response (BW)

Frequency response is measured at the output of the ON channel. For example, when  $V_{IN} = 0$ ,  $V_{EN} = 0$ , and  $D_A$  is the input, the output is measured at  $S1_A$ . All unused analog I/O ports are left open.

### HP8753ES Setup

Average = 4  
RBW = 3 kHz  
 $V_{BIAS} = 0.35\text{ V}$   
ST = 2 s  
P1 = 0 dBm

## PARAMETER MEASUREMENT INFORMATION



† A 50-Ω termination resistor is needed for the Network Analyzer.

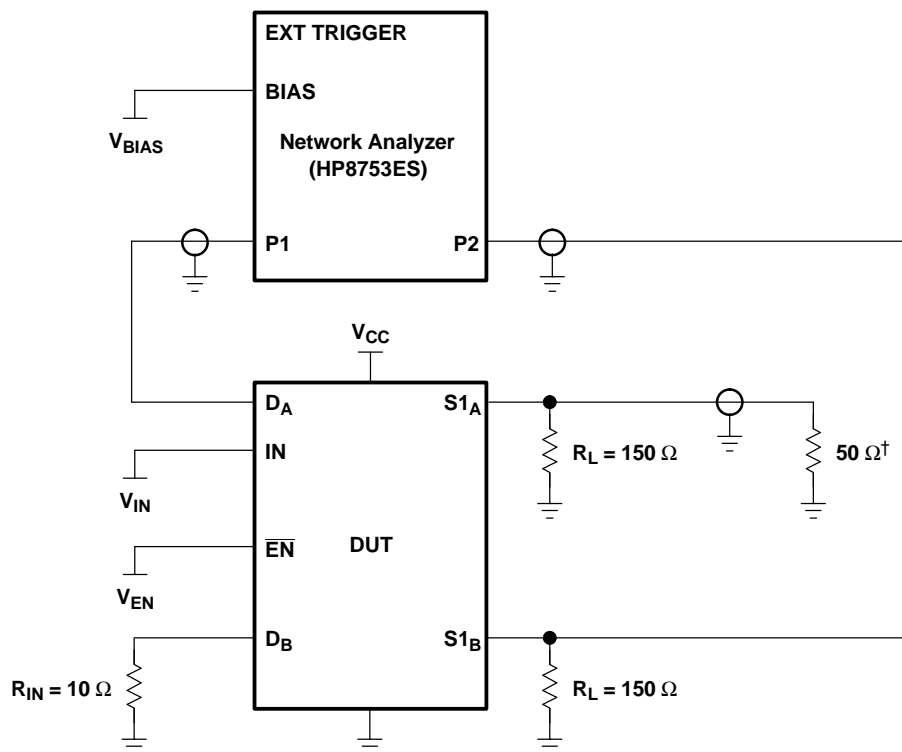
**Figure 8. Test Circuit for Crosstalk ( $X_{TALK}$ )**

Crosstalk is measured at the output of the nonadjacent ON channel. For example, when  $V_{IN} = 0$ ,  $V_{EN} = 0$ , and  $D_A$  is the input, the output is measured at  $S1_B$ . All unused analog input (D) ports and output (S) ports are connected to GND through 10-Ω and 50-Ω pulldown resistors, respectively.

### HP8753ES Setup

Average = 4  
RBW = 3 kHz  
 $V_{BIAS} = 0.35\text{ V}$   
ST = 2 s  
P1 = 0 dBm

## PARAMETER MEASUREMENT INFORMATION



† A 50-Ω termination resistor is needed for the network analyzer.

**Figure 9. Test Circuit for Off Isolation ( $O_{IRR}$ )**

Off isolation is measured at the output of the OFF channel. For example, when  $V_{IN} = V_{CC}$ ,  $V_{EN} = 0$ , and  $D_A$  is the input, the output is measured at  $S1_A$ . All unused analog input (D) ports are left open, and output (S) ports are connected to GND through 50-Ω pulldown resistors.

### HP8753ES Setup

Average = 4  
RBW = 3 kHz  
 $V_{BIAS} = 0.35$  V  
ST = 2 s  
P1 = 0 dBm

## PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">TS3V330D</a>	Active	Production	SOIC (D)   16	40   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TS3V330
TS3V330D.B	Active	Production	SOIC (D)   16	40   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TS3V330
<a href="#">TS3V330DBQR</a>	Active	Production	SSOP (DBQ)   16	2500   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TF330
TS3V330DBQR.B	Active	Production	SSOP (DBQ)   16	2500   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TF330
<a href="#">TS3V330DGVR</a>	Active	Production	TVSOP (DGV)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TF330
TS3V330DGVR.B	Active	Production	TVSOP (DGV)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TF330
<a href="#">TS3V330DR</a>	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TS3V330
TS3V330DR.B	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TS3V330
<a href="#">TS3V330PW</a>	Obsolete	Production	TSSOP (PW)   16	-	-	Call TI	Call TI	-40 to 85	TF330
<a href="#">TS3V330PWR</a>	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TF330
TS3V330PWR.B	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TF330
<a href="#">TS3V330RGYR</a>	Active	Production	VQFN (RGY)   16	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TF330
TS3V330RGYR.B	Active	Production	VQFN (RGY)   16	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TF330

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## TAPE AND REEL INFORMATION



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS3V330DBQR	SSOP	DBQ	16	2500	330.0	12.5	6.4	5.2	2.1	8.0	12.0	Q1
TS3V330DGVR	TVSOP	DGV	16	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
TS3V330DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TS3V330PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TS3V330RGYR	VQFN	RGY	16	3000	330.0	12.4	3.8	4.3	1.5	8.0	12.0	Q1



## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS3V330DBQR	SSOP	DBQ	16	2500	353.0	353.0	32.0
TS3V330DGVR	TVSOP	DGV	16	2000	353.0	353.0	32.0
TS3V330DR	SOIC	D	16	2500	340.5	336.1	32.0
TS3V330PWR	TSSOP	PW	16	2000	353.0	353.0	32.0
TS3V330RGYR	VQFN	RGY	16	3000	353.0	353.0	32.0

## TUBE



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TS3V330D	D	SOIC	16	40	507	8	3940	4.32
TS3V330D.B	D	SOIC	16	40	507	8	3940	4.32

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



4040047-6/M 06/11

- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
  - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
  - E. Reference JEDEC MS-012 variation AC.

## DGV (R-PDSO-G\*\*)

## PLASTIC SMALL-OUTLINE

24 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.  
 D. Falls within JEDEC: 24/48 Pins – MO-153  
 14/16/20/56 Pins – MO-194



## PACKAGE OUTLINE

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

# EXAMPLE BOARD LAYOUT

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 10X



4220204/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE: 10X

4220204/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



**DBQ0016A**

# PACKAGE OUTLINE

**SSOP - 1.75 mm max height**

SHRINK SMALL-OUTLINE PACKAGE



4214846/A 03/2014

## NOTES:

- Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
- This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 inch, per side.
- This dimension does not include interlead flash.
- Reference JEDEC registration MO-137, variation AB.

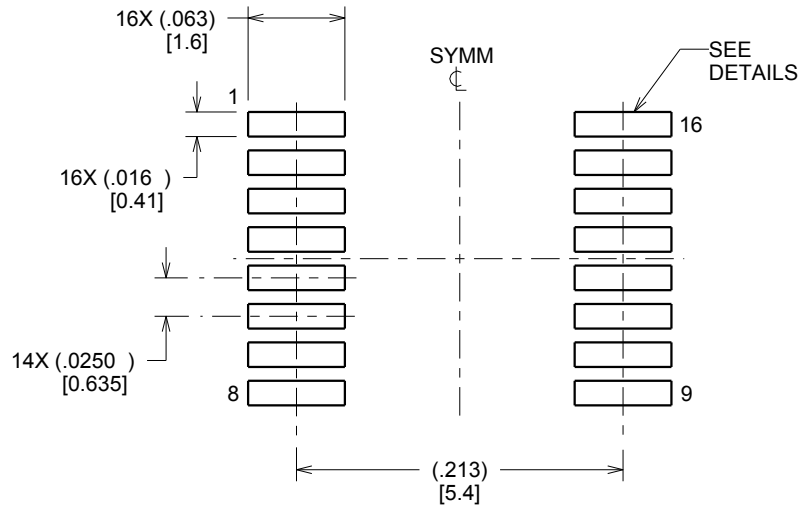


# EXAMPLE BOARD LAYOUT

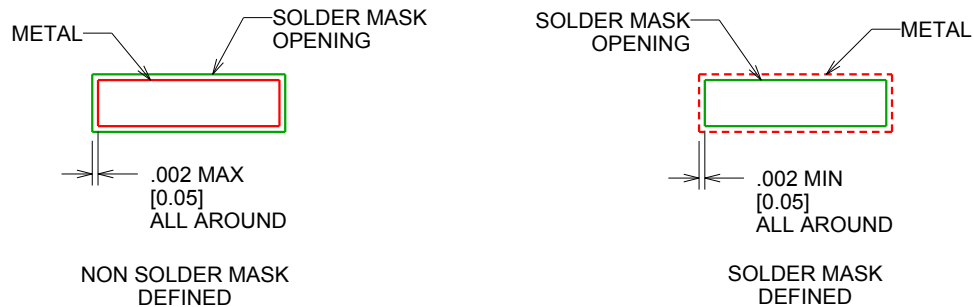
DBQ0016A

SSOP - 1.75 mm max height

SHRINK SMALL-OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
SCALE:8X



SOLDER MASK DETAILS

4214846/A 03/2014

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

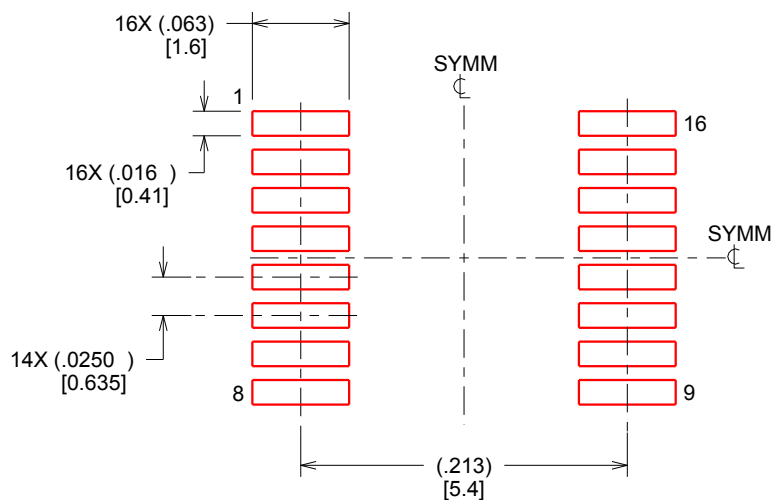
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

## EXAMPLE STENCIL DESIGN

DBQ0016A

SSOP - 1.75 mm max height

SHRINK SMALL-OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON .005 INCH [0.127 MM] THICK STENCIL  
SCALE:8X

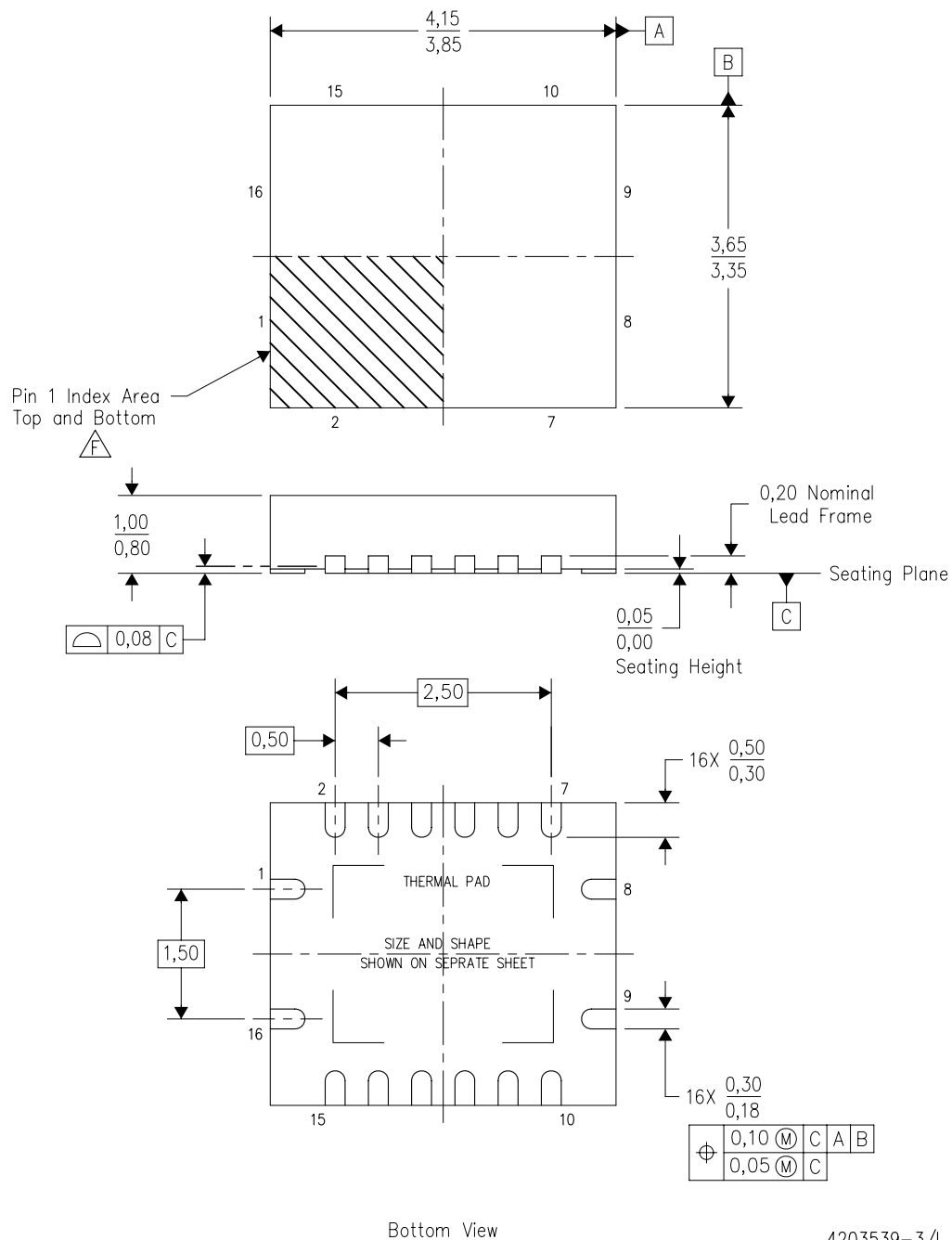
4214846/A 03/2014

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

RGY (R-PVQFN-N16)

PLASTIC QUAD FLATPACK NO-LEAD



4203539-3/I 06/2011

- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - This drawing is subject to change without notice.
  - QFN (Quad Flatpack No-Lead) package configuration.
  - The package thermal pad must be soldered to the board for thermal and mechanical performance.
  - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- F** Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- Package complies to JEDEC MO-241 variation BA.

RGY (R-PVQFN-N16)

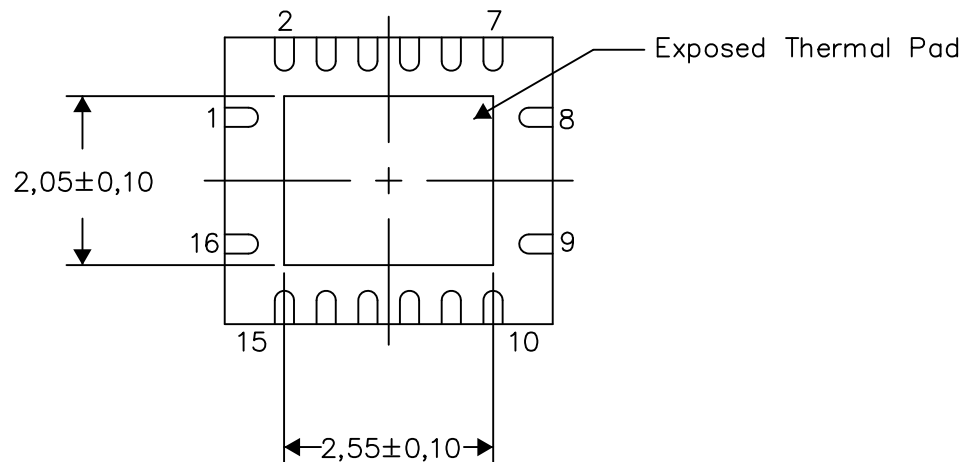
PLASTIC QUAD FLATPACK NO-LEAD

## THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.

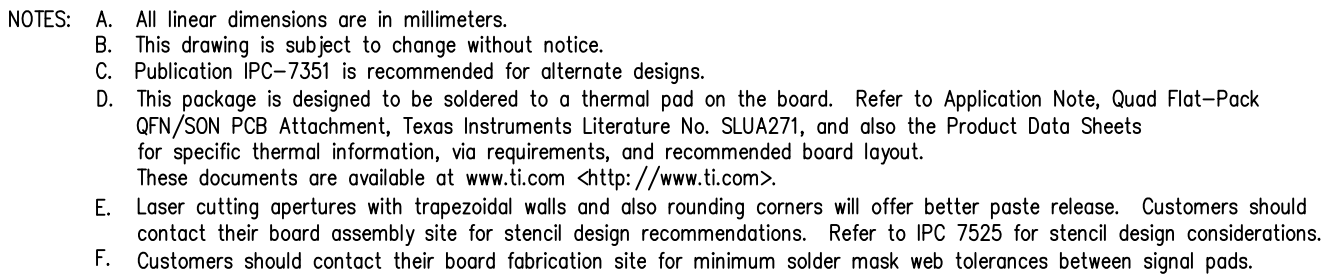


Bottom View

Exposed Thermal Pad Dimensions

4206353-3/P 03/14

NOTE: All linear dimensions are in millimeters



## IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#), [TI's General Quality Guidelines](#), or other applicable terms available either on [ti.com](#) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2025, Texas Instruments Incorporated

Last updated 10/2025